## 

# PJD45P04

## 40V P-Channel Enhancement Mode MOSFET

Current

### Voltage

#### Features

•  $R_{DS(ON)}$ ,  $V_{GS}$ @-10V,  $I_D$ @-15A<17m $\Omega$ 

-40 V

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-4.5V, I<sub>D</sub>@-10A<25mΩ</li>
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

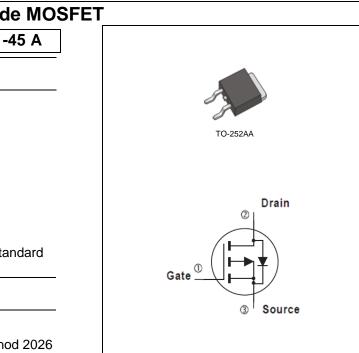
#### **Mechanical Data**

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams

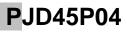
### **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-40	- v	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C		-45	A	
	$T_{\rm C}=100^{\circ}{\rm C}$	I <sub>D</sub>	-28		
Pulsed Drain Current (Note 1)	T <sub>c</sub> =25°C	I <sub>DM</sub>	-135		
Power Dissipation	T <sub>C</sub> =25°C	D	63	14/	
	$T_{C}=100^{\circ}C$	PD	25	W	
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C		-8.5		
	T <sub>A</sub> =70°C	I <sub>D</sub>	-7	A	
Power Dissipation	T <sub>A</sub> =25°C	_	2.0		
	T <sub>A</sub> =70°C	PD	1.3	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	R <sub>θJC</sub>	2.0	°C/W	
	Junction to Ambient	R <sub>θJA</sub>	62.5		

• Limited only By Maximum Junction Temperature





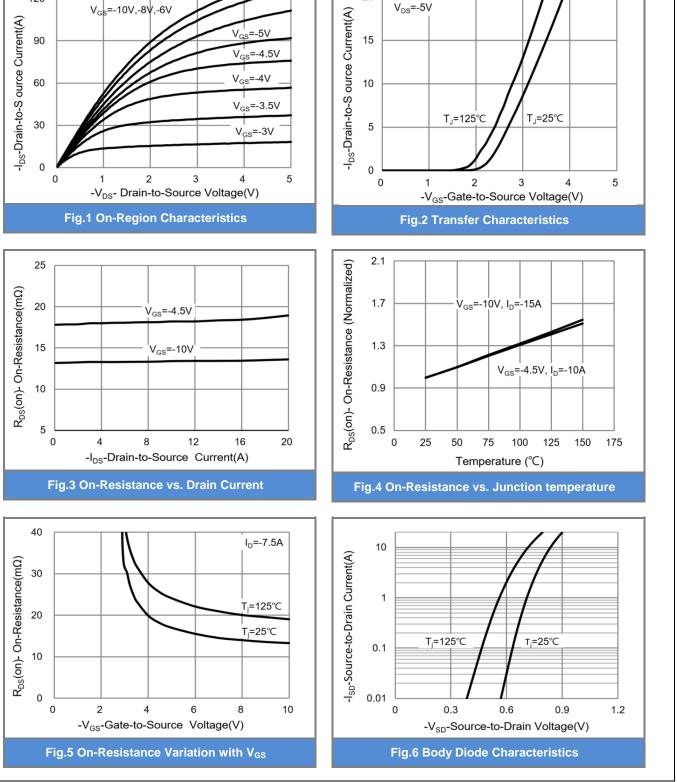


#### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-40	-	-	N/
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250$ uA	-1	-1.6	-2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-15A	-	14	17	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-10A	-	20	25	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	$V_{DS}$ =-32V, I <sub>D</sub> =-10A, $V_{GS}$ =-4.5V <sup>(Note 1,2)</sup>	-	19	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	5.3	-	
Gate-Drain Charge	$Q_{gd}$		-	6.6	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V, f=1MHZ	-	2030	-	pF
Output Capacitance	Coss		-	190	-	
Reverse Transfer Capacitance	Crss		-	139	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	8.6	-	ns
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =-20V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω	-	9.6	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	77	-	
Turn-Off Fall Time	t <sub>f</sub>		-	39	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-45	A
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-0.71	-1	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



20

120

**TYPICAL CHARACTERISTIC CURVES** 

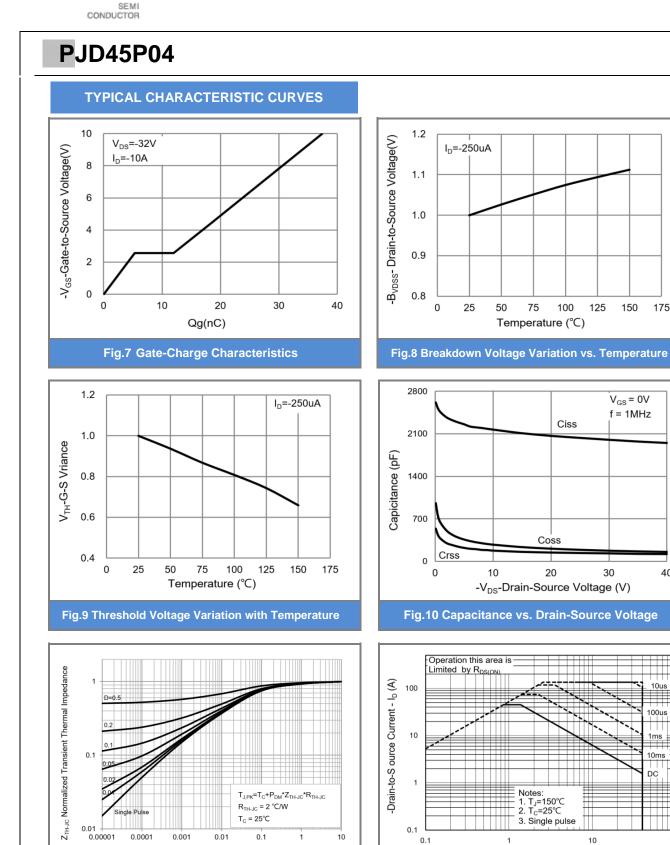
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t, Pulse Width PW (s)

Fig.11 Maximum Safe Operating Area

PANJ



125

150

 $V_{GS} = 0V$ 

f = 1MHz

30

10

-V<sub>DS</sub>-Drain-Source Voltage (V)

Fig.12 Normalized Thermal Transient Impedance

175

40

10us

100us

1ms

10ms DC

100



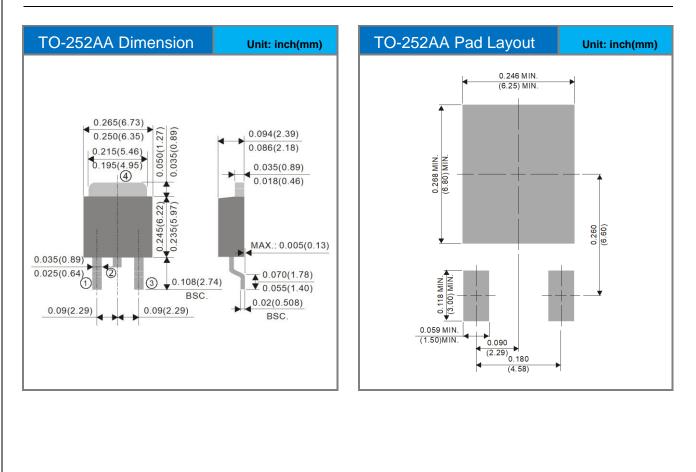


## **PJD45P04**

#### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type Marking		Version
PJD45P04_L2_00001	TO-252AA	3,000pcs / 13" reel	D45P04	Halogen free

#### **Packaging Information & Mounting Pad Layout**







## **PJD45P04**

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